BTI

OVERVIEW DATA SHEET: BT2577

2.4GHz RF TRANSCEIVER

Features

- 2.4GHz ISM Band RF Transceiver
- ETS 300 328
- Air Interface complies with FCC Part 15 Rules
- Power Management for Minimizing Supply Current
- Power Supply 3.0V <u>+</u> 10%
- Power Control for TX tranmission
- Operating Temperature: -40°C to +85°C

Functions

Receiver:

Low Noise Amplifier (LNA) w/ Gain Control Image Reject RF Mixer RSSI GFSK Demodulator FM (analog)/FSK (digital) output

Transmitter:

FM/FSK Modulator Upconversion Mixer Power Amplifier with Power Control (9 dBm/ 16dBm)

RF VCO

Applications

- 2.4GHz ISM Band Applications
- Wireless local loop subscriber unit
- BluetoothTM wireless application products
- HomeRFTM wireless application products

General Description

The BT2577 is a high-performance transceiver for worldwide 2.4GHz ISM band applications. It includes on-chip features such as the LNA, Modulator / Demodulator, RF VCO, image-rejection mixer and upconversion mixer.

The receiver section of the BT2577 contains a Low Noise Amplifier (LNA), a downconverter (image rejection mixer), IF AMP, Limiter, FM demodulator, data slicer, RSSI, and RF Voltage Control Oscillator (VCO). The receiver is designed to require a minimal number of external components and pin count for cost effectiveness.

The transmitter section will share the same RF VCO with the receiver, but also includes FSK modulator, upconverter, and power amplifier. The transmitter also requires minimal external components for reducing mass production cost.

Since there is no IF or RF PLL included on the BT2577, the design engineer can choose the most appropriate RF-IF PLL to use based upon their unique system power consumption, cost and performance requirements. Keeping the PLL Synthesizer separate from the rest of the RFIC Transceiver also makes it possible to accomplish lower noise, and higher peformance designs, due to the improved isolation between the high and low frequency synthesizer sections and the RX and TX signal conversion chains.

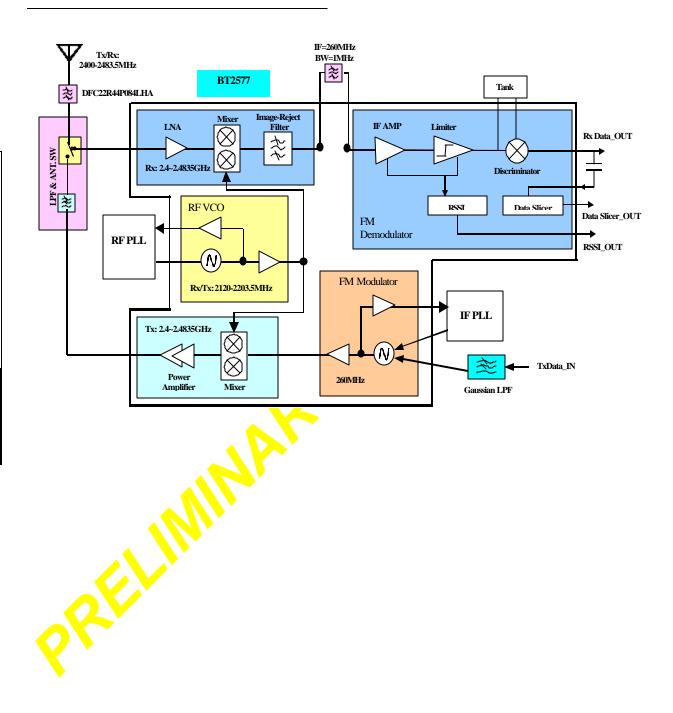
Ordering Information

BT2577 2.4GHz RF Transceiver

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Block Diagram



Absolute Maximum Ratings

Parameters	Value	Unit
Supply voltage	3.0 <u>+</u> 10%	V
Storage temperature	-40 to 85	°C

Electrical Characteristics

Parameter	Min	Тур	Max	Unit	Remarks	Note
Power supply voltage (Vcc)	2.7	3.0	3.3	V		
Power supply current (Rx):		18.7		mA		
Power supply current (Tx): - High power (16dBm) mode: - Low power (9dBm) mode:		31.6 19.8		mA mA	6	
Power supply current (RFVCO):		17.4		mA	∠	

Design Specifications

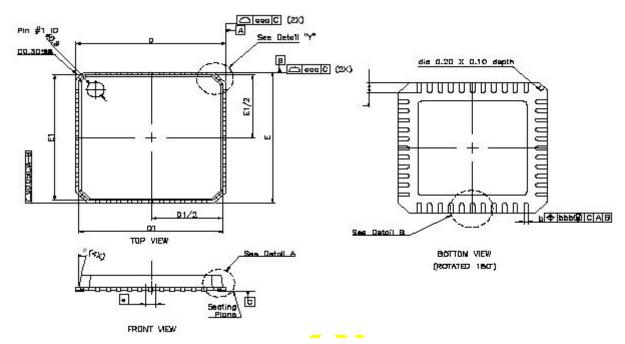
TX SPECIFICATIONS

Parameter	Min	Тур	Max	Unit	Remarks	Note
General						
RF Frequency	2400	2442	2484	MHz		
RF Output Power High Power Mode Low Power Mode	1	16 9		dBm dBm		
DC Current High Power Mode Low Power Mode		31.6 19.8		mA mA		

RX SPECIFICATIONS

Parameter	Min	Тур	Max	Unit	Remarks	Note
General						
RF Frequency	2400	2442	2484	MHz		
IF Frequency		260		MHz		
Current Consumption	11.4	18.7	23.4	mA		
Input 1dB Compression Point		-23.8		dBm		
IIP3		-19.7		dBm		
RF Sensitivity		-91		dBm		
RSSI Sensitivity		-91		dBm		

PACKAGE INFORMATION

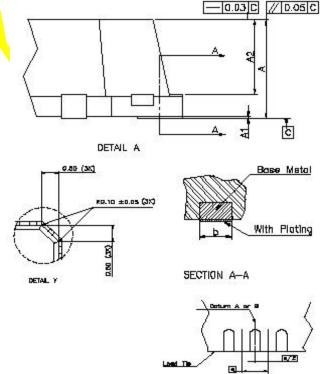


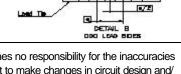
DIMENSION TABLE (44L QLP 7X7 BODY)

SYMBOL	SPECIFICATION	DESCRIPTION
Α	1.0 MAX.	Package Seated Height
A1	5µm — 20µm	Stand-off
A2	0.70±0.08	Mold Cop Thickness
D	7.00 ±0.10	"U noisnemib lonimet
D1	6.75 ±0.10	Package length
E	7.00 ±0.10	Terminal Dimension "E"
E1	6.75 ±0.10	Package width
Ь	0.23 ±0.04	Lead width (after plate)
ь1	0.20 BSC	Lead width (before plate)
е	0.50 BSC	Lead pitch
N	44	Lead count
L	0.55 ±0.10	Lead foot length
6	11°±1	Package draft angle
aaa	0.05	Package body side alignment
bbb	0.05	Ld foot length alignment
X ** **	400000	

- 1. Controlling dimension are in millimeter (mm)
- 2. Top package body corner radius to be 0.15±806
- Microgap visible by 45% shall not be allowed.
 Lead tip burn shall be 0.03 maximum. (Horizontal burn)
- 5. Vertical burn shall be not allowed 6. Interlead (window) flash remain after thirm shall be at
- 0.125 maximum. Intrusion on pockage body is not allowed.
 7. Gate residue shall not exceed 0.125 from the pockage body.
- B. Pin #1 count orientation shall be at counterclockwise
- direction as viewed in live-bug position.

 9. Package surface raughness at 0.9µm ±0.30
- 10. Gate burr remain after singulation shall be at 0.20 maximum.





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